

ASIPs around the MCU Application Specific Integrated Products

Cyril Borchard – Technical Marketing – Power Discrete Products July 2020

Product lineup



Product lineup

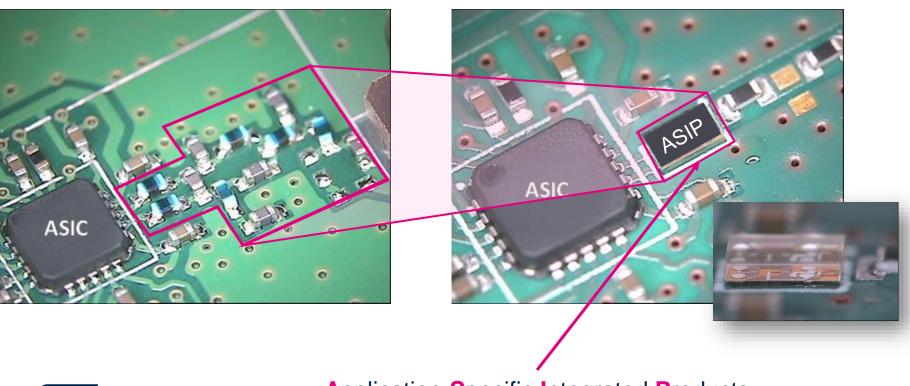
TVS Lightning **Automotive ASIP ESD** protections EOS 8/20 µs **Current limiters** protections protections EOS 10/1000 µs Clamping 400 W **Current limiting** Auto dataline **xDSL EMI filters** 10/1000 µs termination **ESD** arrays 600 W High speed Auto load Common mode **SLIC** $10/1000 \, \mu s$ port protections dump filters Smart ASIP for Rail to rail 1500 W Auto power rail Ethernet interface 10/1000 µs **TVS** protections function Single line 3000 W Custom Telecom lines protections $10/1000 \, \mu s$ integration Dataline Discrete surge <24 A 8/20 µs suppressors

Power line >24 A 8/20 µs





- Design simplification
- Integration



- Integration of capacitors, inductors and resistors and protections
- Size reduction
- BOM reduction
- Design simplification
 - **Performance** optimization
- Reliability improvement



Application Specific Integrated Products

MIM capacitors **Resistors Inductors** • From <1 pF to 100+ nF capacitors</p> • From 1 Ω to few hundreds of $k\Omega$ • Up to 140 nH • 0.6 nF/mm² \pm 20% tolerance • From ± 5% to ± 20% tolerance • Up to 10 µm thickness double layer inductor • 2-5 nF/mm² \pm 10% tolerance • From 35 Ω /sq ± 10% to few k Ω /sq ±20% → high Q-factor • 150 nF/mm² ± 20% tolerance (3D caps*) Better <± 0.5% matching Tunable Caps 0.5 pF to 60 pF Inductor • Matching $< \pm 0.5\%$ Resistor Capacitor Dielectric Insulator

15 kV ESD Clamping diode

ESD protections

- IEC 61000-4-2 level 4 system-standard compliance
- 6 V & 14 V breakdown voltages
- Uni & bidirectional structures
- From 100 pF to 0.25 pF capacitance for High Bandwidth



* The 3D cap technology only allows for integration of highdensity capacitors. No other passive or active components can be integrated on the same die (see slide 9).

Silicon Substrate



SHORT TIME TO SAMPLES

~8 weeks (depending on complexity)



BETTER PERFORMANCE THAN DISCRETES

Less parasitics / better matching



CUSTOMIZABLE & FLEXIBLE SOLUTION

Multi Product Wafer for best optimization



SMALLER THAN DISCRETES

Up to 70%



LOWER COST THAN DISCRETES

Reduces BOM, PCB size, improves quality

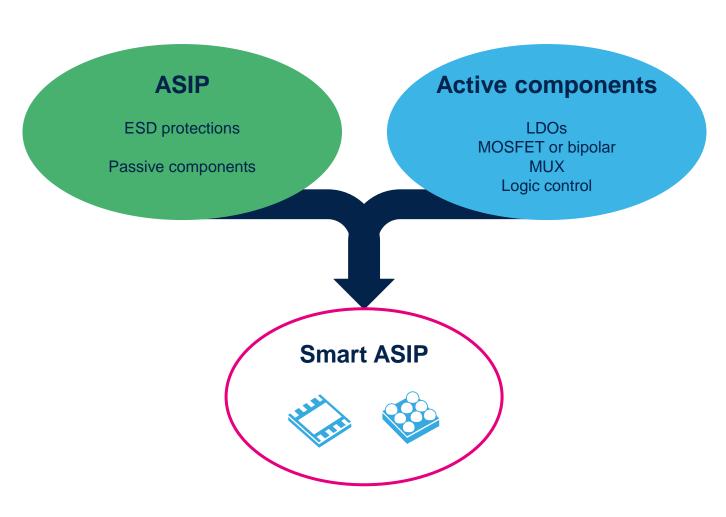


BALISTIC QUALIFICATION



What is a smart ASIP?

- More active functionalities added
- When discrete circuits become:
 - Too complex
 - Too big
 - Too expensive
 - Not performant enough

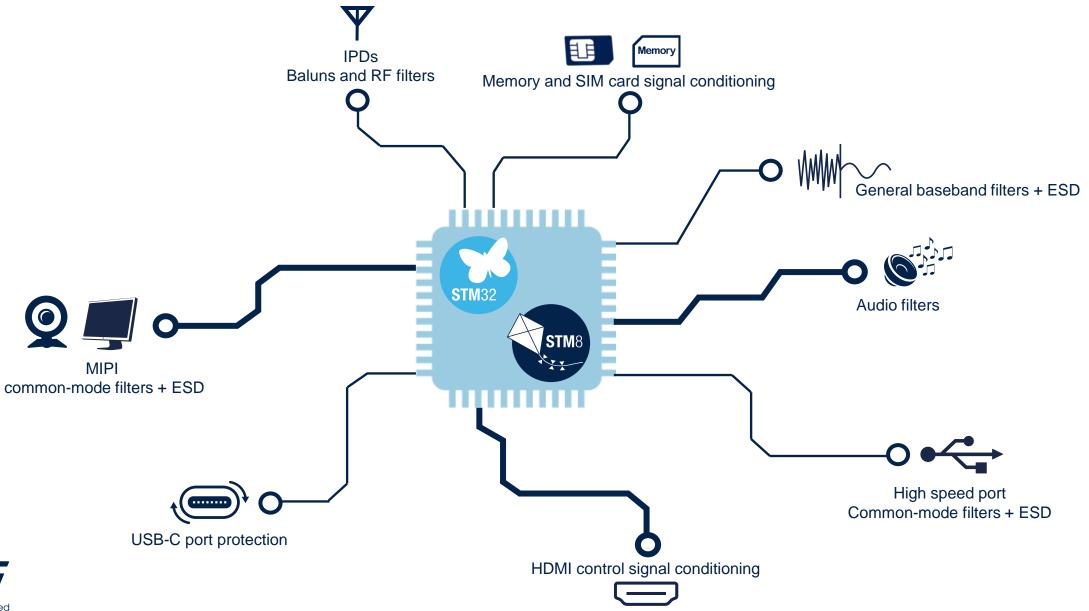




Typical ASIPs around the MCU

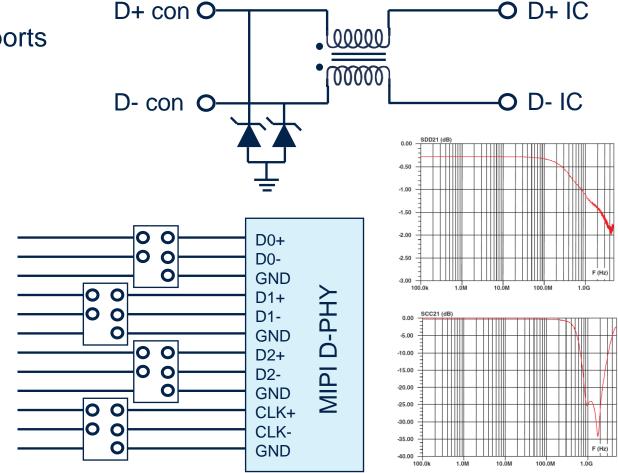


Typical ASIPs around the MCU



Common mode filters + ESD

- ECMF = combination of ESD protection and Common-Mode choke
 - 2 to 6 line devices
 - Applications: high-speed communication ports
 - USB 3.x
 - HDMI 2.x
 - MIPI
 - Goals:
 - Protect against IEC61000-4-2 level 4 ESD
 - Suppress common-mode noise
 - Keep signal integrity
 - Save space on PCB

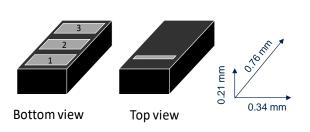


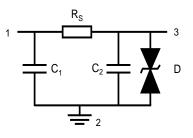


Example: ECMF02-2BF3 on MIPI

General baseband filters + ESD

- Example: EMIF01-1008AF4
 - Low pass filter with integrated ESD protection





• MiM⁽¹⁾ capacitors

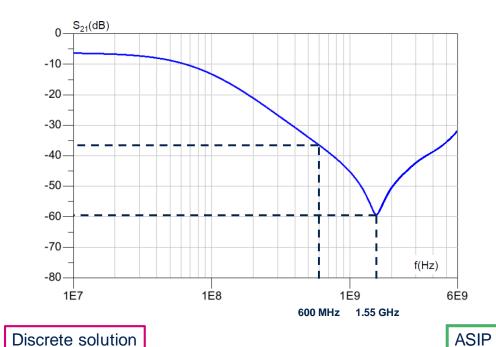


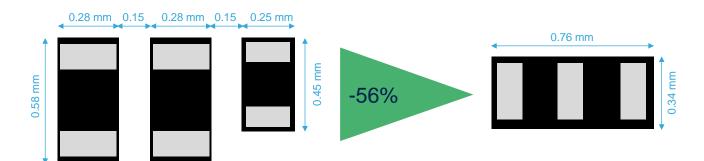
•
$$R_{S}(typ) = 100 \Omega$$

Total line capacitance:

•
$$C_{line}(typ) = C_1 + C_2 + C_D = 80 pF$$

- ESD protection:
 - 8 kV contact discharge IEC 610000-4-2 on pin 3
 - Exceeding HBM 2kV min on pin 1



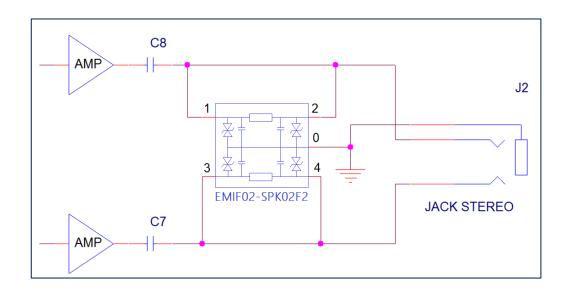


0.59 mm²





Audio filters





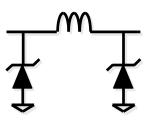
Flip-chip 4 bumps

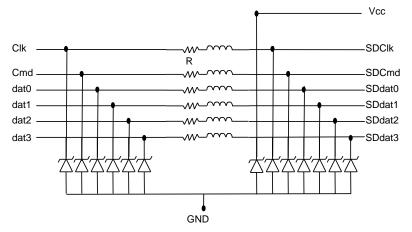
Needs for data lines	Product key parameters	ST solutions	
Analog signal	Bidirectional serial res of 0.07 Ω^*		
Rejection of Bluetooth and WiFi frequencies	Rejection >40 dB at 900 MHz Rejection >20 dB at 2.4 GHz	EMIF02-SPK02F2 EMIF02-SPK03F2*	
IEC 61000-4-2 level 4	Contact discharge: 8 kV Air discharge: 15 kV		

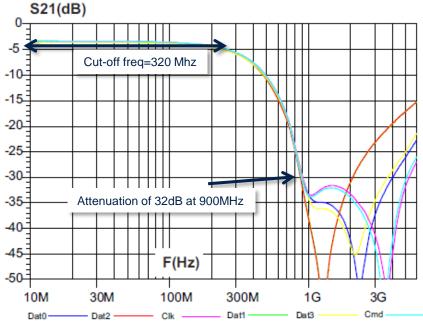






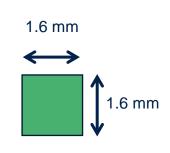


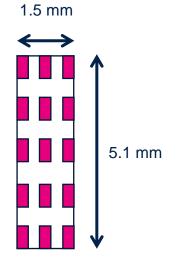






SD and SIM cards





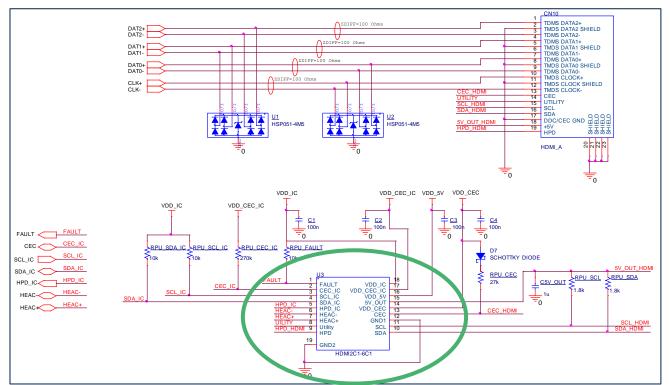
ASIP: 2.56 mm²

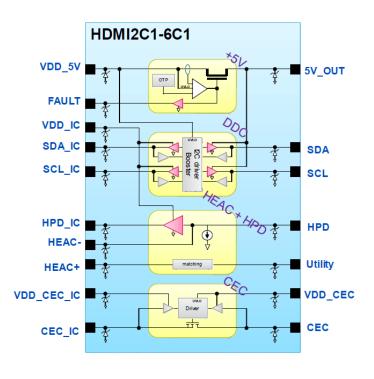
Discrete: 7.7 mm²

18 x 0201

3 times smaller

HDMI control signal conditioning



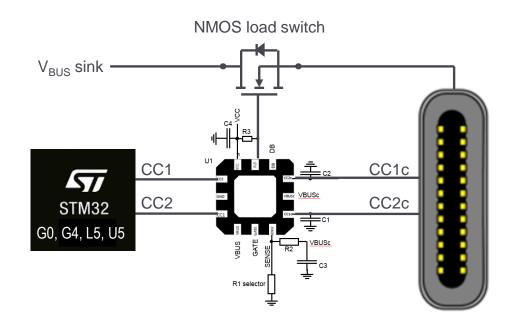


	Application needs	Product key parameters	ST solutions	
_	Control lines: compliance with certification standard	8 kV IEC61000-4-2 ESD protections		
		DDC bi-directional signal conditioning and dynamic pull-up		
		CEC bi-directional level-shifter, backdrive protection	LIDMI2C4 CC4	
		HEAC link protection and line matching	HDMI2C1-6C1	
		HPD pull-down, signal conditioning with level -shifting and backdrive protection		
		Short-circuit protection on 5V output		



USB type C port protection

- TCPP series (USB Type C Port Protection)
 - V_{BUS} power path, OVP and ESD protection
 - Comes with a Nucleo shield
 - Main features
 - ESD protection for CC1, CC2 and V_{BUS}
 - IEC61000-4-2 Level 4 compliant
 - 24 V OVP on CC lines against short-to-V_{BUS} overvoltage
 - 22 V OVP on V_{BUS}
 - Integrated gate driver for external V_{BUS} load-switch
 - OTP at 135 °C
 - QFN 12-pin package 3 x 3 mm (pitch 0.5 mm)









Integrated Passive Devices

- Products (non-exhaustive list)
 - RF filters
 - RF diplexers or triplexers
 - RF couplers
 - Baluns
 - RF matching networks
- Applications (non-exhaustive list)
 - Any application requiring RF filtering functions



























Conclusion



Conclusion

 ST offers a large variety ASIPs and IPDs for advanced applications in the IoT market.

Those are ideal companion chips for MCUs.

 ASIPs allow design simplification as well as space-saving through higher integration.

 IPDs allow high integration of passive components to design performant pricecompetitive RF filters.



Thank you



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